# **ONSEM**Í,

# Single Silicon Switching Diode

## M1MA141KT1G, M1MA142KT1G

This Silicon Epitaxial Planar Diode is designed for use in ultra high speed switching applications. This device is housed in the SC–70 package which is designed for low power surface mount applications.

#### Features

- Fast  $t_{rr}$ , < 3.0 ns
- Low C<sub>D</sub>, < 2.0 pF
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS** (T<sub>A</sub> = $25^{\circ}$ C)

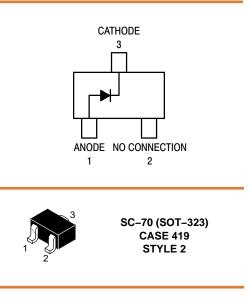
Rating	Symbol	Value	Unit
Reverse Voltage M1MA141KT1 M1MA142KT1	V <sub>R</sub>	40 80	Vdc
Peak Reverse Voltage M1MA141KT1 M1MA142KT1	V <sub>RM</sub>	40 80	Vdc
Forward Current	١ <sub>F</sub>	100	mAdc
Peak Forward Current	I <sub>FM</sub>	225	mAdc
Peak Forward Surge Current	I <sub>FSM</sub> (Note 2)	500	mAdc

#### THERMAL CHARACTERISTICS

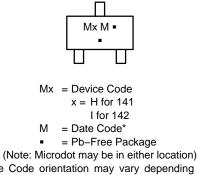
Rating	Symbol	Max	Unit
Power Dissipation	PD	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>stg</sub>	-55 ~ +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. t = 1 sec



#### MARKING DIAGRAM



\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
M1MA141KT1G	SC-70 (Pb-Free)	3000/Tape & Reel

#### DISCONTINUED (Note 1)

	( )	
M1MA142KT1G	SC-70	3000/Tape & Reel
	(Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

 DISCONTINUED: This device is not recommended for new design. Please contact your onsemi representative for information. The most current information on this device may be available on <u>www.onsemi.com</u>.

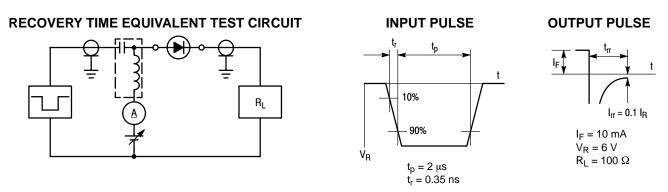
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### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = $25^{\circ}$ C)

Characteristic	Condition	Symbol	Min	Max	Unit
Reverse Voltage Leakage Current M1MA141KT1 M1MA142KT1	V <sub>R</sub> = 35 V V <sub>R</sub> = 75 V	۱ <sub>R</sub>	-	0.1	μAdc
Forward Voltage	I <sub>F</sub> = 100 mA	V <sub>F</sub>	-	1.2	Vdc
Reverse Breakdown Voltage M1MA141KT1 M1MA142KT1	I <sub>R</sub> = 100 μA	V <sub>R</sub>	40 80	-	Vdc
Diode Capacitance	V <sub>R</sub> = 0, f = 1.0 MHz	CD	-	2.0	pF
Reverse Recovery Time (Figure 1)	$    I_F = 10 \text{ mA},  \text{V}_R = 6.0 \text{ V}, \\ \text{R}_L = 100 \ \Omega,  \text{I}_{rr} = 0.1  \text{I}_R $	t <sub>rr</sub> (Note 3)	-	3.0	ns

3. t<sub>rr</sub> Test Circuit

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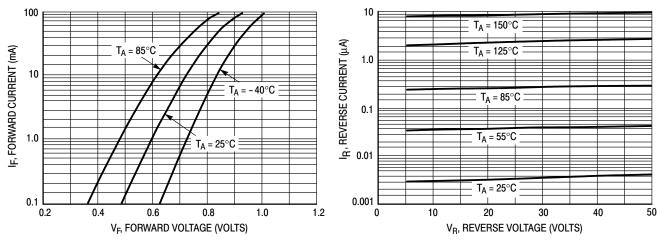


Figure 2. Forward Voltage

Figure 3. Reverse Current

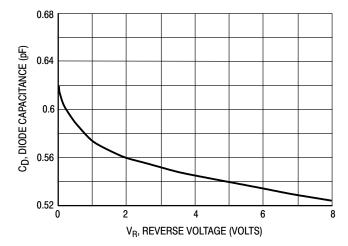
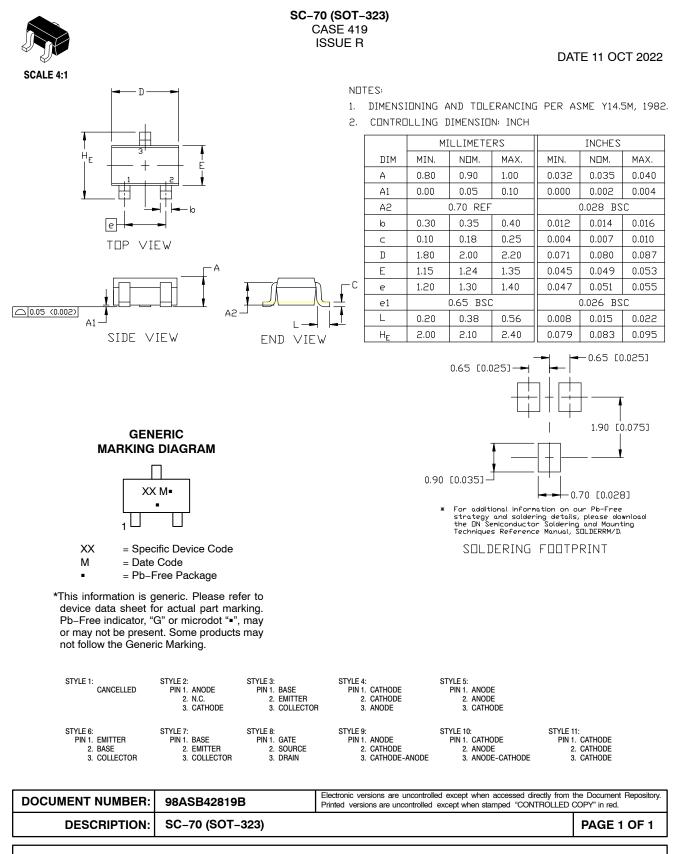


Figure 4. Diode Capacitance

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